



Welcome to [E-XFL.COM](https://www.e-xfl.com)

Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

| | |
|--------------------------------|---|
| Product Status | Obsolete |
| Number of LABs/CLBs | - |
| Number of Logic Elements/Cells | - |
| Total RAM Bits | 36864 |
| Number of I/O | 93 |
| Number of Gates | 250000 |
| Voltage - Supply | 1.425V ~ 1.575V |
| Mounting Type | Surface Mount |
| Operating Temperature | 0°C ~ 85°C (TJ) |
| Package / Case | 208-BFQFP |
| Supplier Device Package | 208-PQFP (28x28) |
| Purchase URL | https://www.e-xfl.com/product-detail/microsemi/m1afs250-1pq208 |

2 – Device Architecture

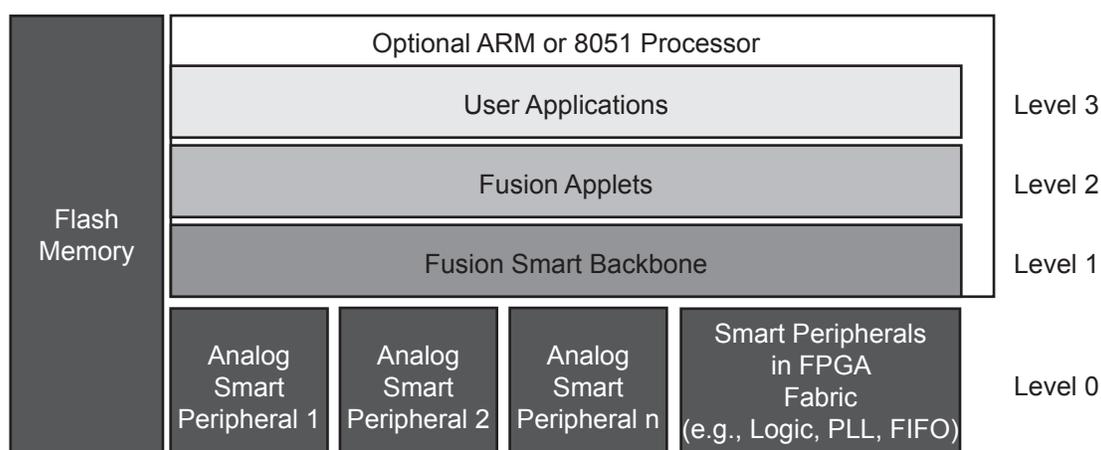
Fusion Stack Architecture

To manage the unprecedented level of integration in Fusion devices, Microsemi developed the Fusion technology stack (Figure 2-1). This layered model offers a flexible design environment, enabling design at very high and very low levels of abstraction. Fusion peripherals include hard analog IP and hard and soft digital IP. Peripherals communicate across the FPGA fabric via a layer of soft gates—the Fusion backbone. Much more than a common bus interface, this Fusion backbone integrates a micro-sequencer within the FPGA fabric and configures the individual peripherals and supports low-level processing of peripheral data. Fusion applets are application building blocks that can control and respond to peripherals and other system signals. Applets can be rapidly combined to create large applications. The technology is scalable across devices, families, design types, and user expertise, and supports a well-defined interface for external IP and tool integration.

At the lowest level, Level 0, are Fusion peripherals. These are configurable functional blocks that can be hardwired structures such as a PLL or analog input channel, or soft (FPGA gate) blocks such as a UART or two-wire serial interface. The Fusion peripherals are configurable and support a standard interface to facilitate communication and implementation.

Connecting and controlling access to the peripherals is the Fusion backbone, Level 1. The backbone is a soft-gate structure, scalable to any number of peripherals. The backbone is a bus and much more; it manages peripheral configuration to ensure proper operation. Leveraging the common peripheral interface and a low-level state machine, the backbone efficiently offloads peripheral management from the system design. The backbone can set and clear flags based upon peripheral behavior and can define performance criteria. The flexibility of the stack enables a designer to configure the silicon, directly bypassing the backbone if that level of control is desired.

One step up from the backbone is the Fusion applet, Level 2. The applet is an application building block that implements a specific function in FPGA gates. It can react to stimuli and board-level events coming through the backbone or from other sources, and responds to these stimuli by accessing and manipulating peripherals via the backbone or initiating some other action. An applet controls or responds to the peripheral(s). Applets can be easily imported or exported from the design environment. The applet structure is open and well-defined, enabling users to import applets from Microsemi, system developers, third parties, and user groups.



Note: Levels 1, 2, and 3 are implemented in FPGA logic gates.

Figure 2-1 • Fusion Architecture Stack

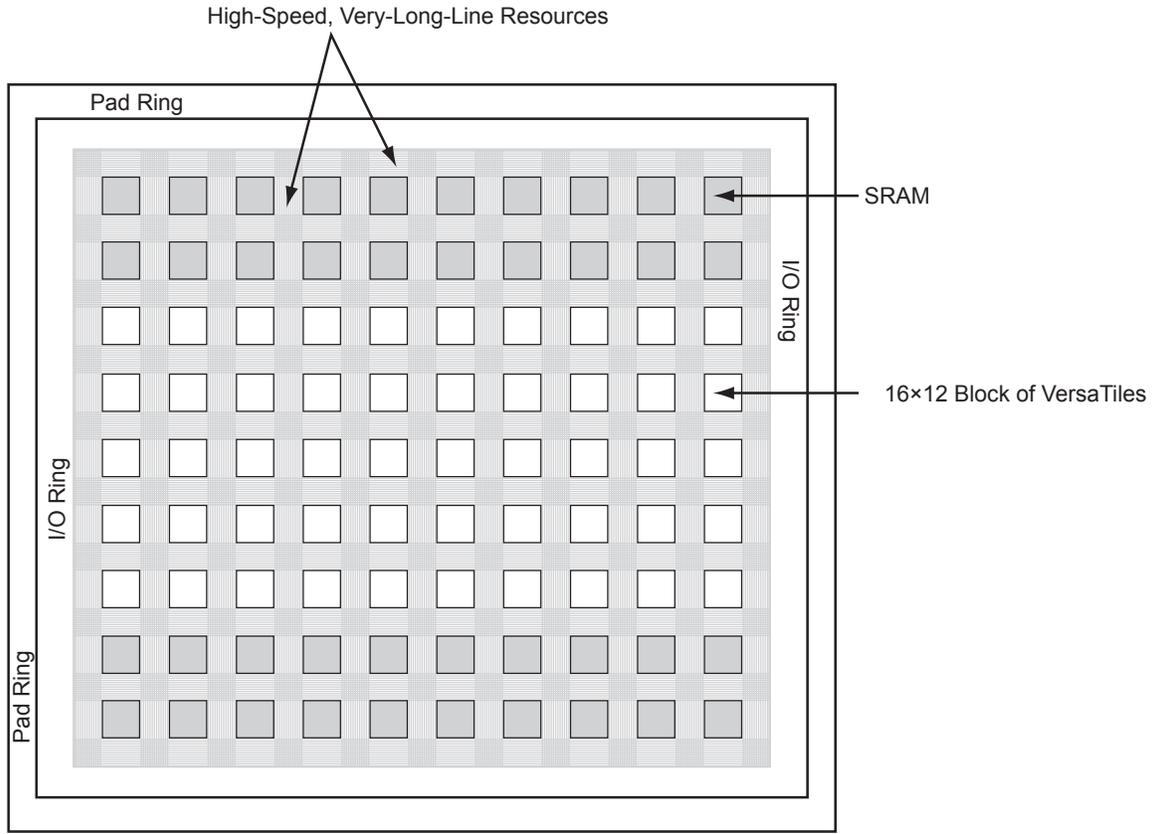


Figure 2-10 • Very-Long-Line Resources

Clocking Resources

The Fusion family has a robust collection of clocking peripherals, as shown in the block diagram in [Figure 2-16](#). These on-chip resources enable the creation, manipulation, and distribution of many clock signals. The Fusion integrated RC oscillator produces a 100 MHz clock source with no external components. For systems requiring more precise clock signals, the Fusion family supports an on-chip crystal oscillator circuit. The integrated PLLs in each Fusion device can use the RC oscillator, crystal oscillator, or another on-chip clock signal as a source. These PLLs offer a variety of capabilities to modify the clock source (multiply, divide, synchronize, advance, or delay). Utilizing the CCC found in the popular ProASIC3 family, Fusion incorporates six CCC blocks. The CCCs allow access to Fusion global and local clock distribution nets, as described in the ["Global Resources \(VersaNets\)"](#) section on page 2-11.

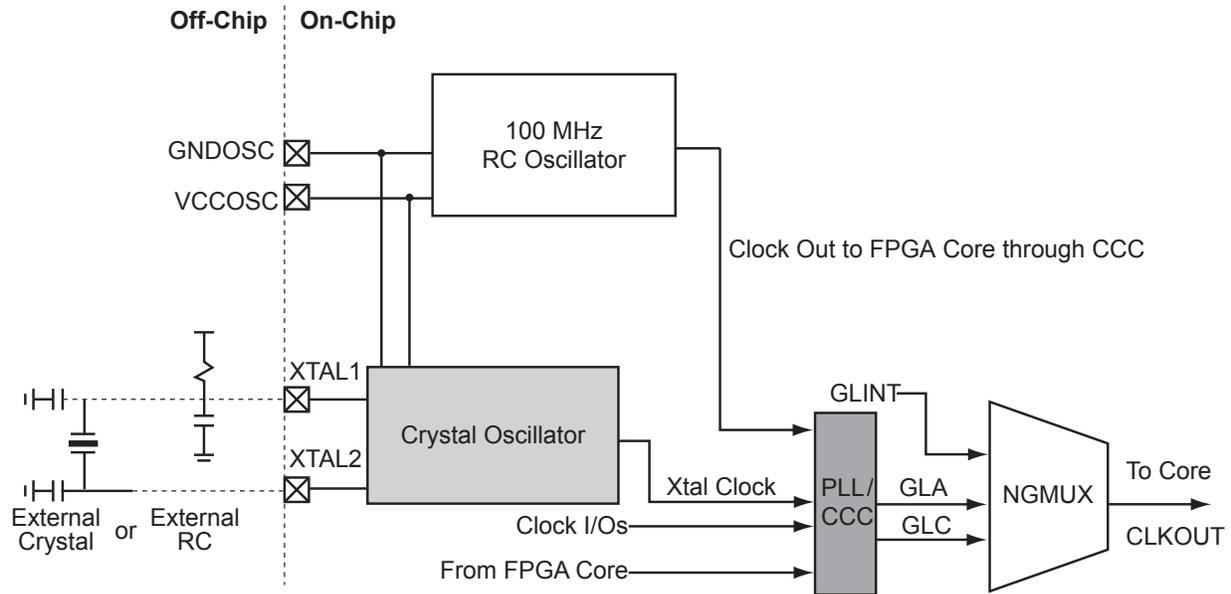


Figure 2-16 • Fusion Clocking Options

Crystal Oscillator

The Crystal Oscillator (XTLOSC) is source that generates the clock from an external crystal. The output of XTLOSC CLKOUT signal can be selected as an input to the PLL. Refer to the "Clock Conditioning Circuits" section for more details. The XTLOSC can operate in normal operations and Standby mode (RTC is running and 1.5 V is not present).

In normal operation, the internal FPGA_EN signal is '1' as long as 1.5 V is present for VCC. As such, the internal enable signal, XTL_EN, for Crystal Oscillator is enabled since FPGA_EN is asserted. The XTL_MODE has the option of using MODE or RTC_MODE, depending on SELMODE.

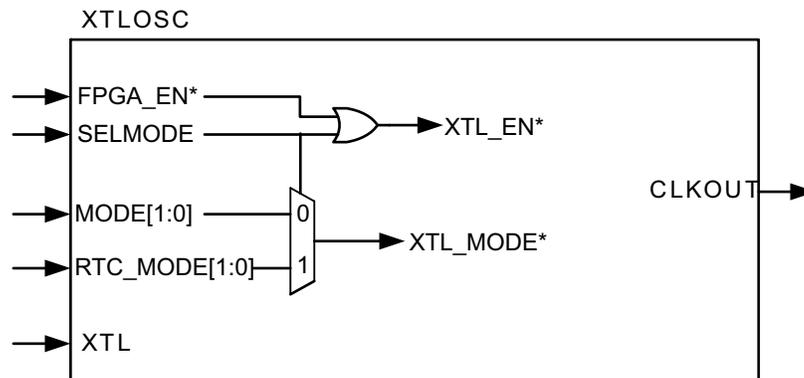
During Standby, 1.5 V is not available, as such, and FPGA_EN is '0'. SELMODE must be asserted in order for XTL_EN to be enabled; hence XTL_MODE relies on RTC_MODE. SELMODE and RTC_MODE must be connected to RTCXTLSEL and RTCXTLMODE from the AB respectively for correct operation during Standby (refer to the "Real-Time Counter System" section on page 2-31 for a detailed description).

The Crystal Oscillator can be configured in one of four modes:

- RC network, 32 KHz to 4 MHz
- Low gain, 32 to 200 KHz
- Medium gain, 0.20 to 2.0 MHz
- High gain, 2.0 to 20.0 MHz

In RC network mode, the XTAL1 pin is connected to an RC circuit, as shown in Figure 2-16 on page 2-18. The XTAL2 pin should be left floating. The RC value can be chosen based on Figure 2-18 for any desired frequency between 32 KHz and 4 MHz. The RC network mode can also accommodate an external clock source on XTAL1 instead of an RC circuit.

In Low gain, Medium gain, and High gain, an external crystal component or ceramic resonator can be added onto XTAL1 and XTAL2, as shown in Figure 2-16 on page 2-18. In the case where the Crystal Oscillator block is not used, the XTAL1 pin should be connected to GND and the XTAL2 pin should be left floating.



Note: *Internal signal—does not exist in macro.

Figure 2-17 • XTLOSC Macro

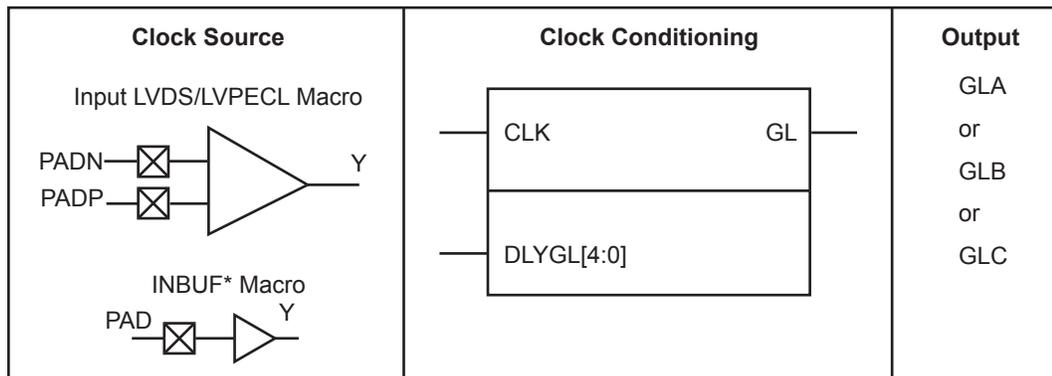
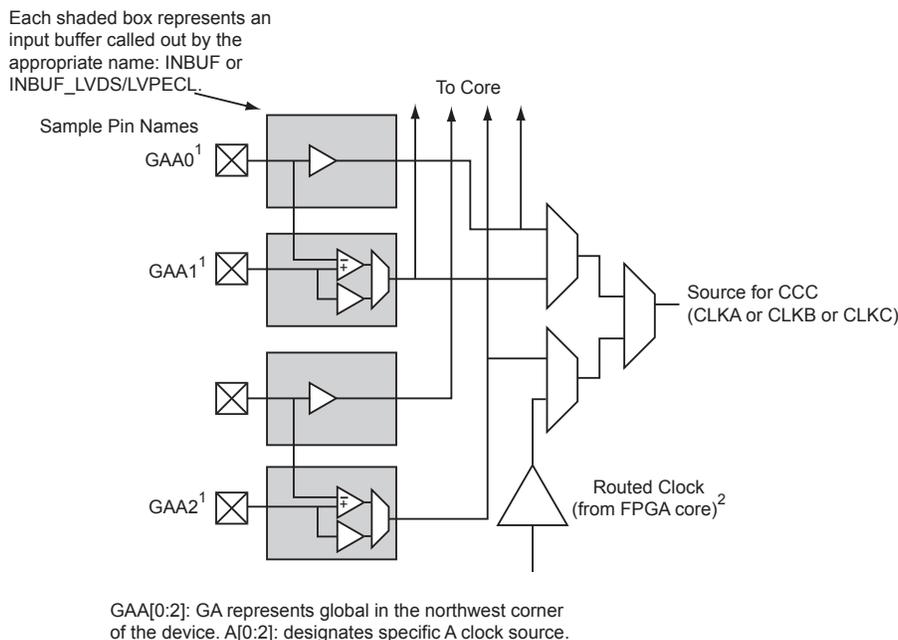


Figure 2-21 • Fusion CCC Options: Global Buffers with Programmable Delay

Global Input Selections

Each global buffer, as well as the PLL reference clock, can be driven from one of the following (Figure 2-22):

- 3 dedicated single-ended I/Os using a hardwired connection
- 2 dedicated differential I/Os using a hardwired connection
- The FPGA core



Notes:

1. Represents the global input pins. Globals have direct access to the clock conditioning block and are not routed via the FPGA fabric. Refer to the "User I/O Naming Convention" section on page 2-158 for more information.
2. Instantiate the routed clock source input as follows:
 - a) Connect the output of a logic element to the clock input of the PLL, CLKDLY, or CLKINT macro.
 - b) Do not place a clock source I/O (INBUF or INBUF_LVPECL/LVDS) in a relevant global pin location.
3. LVDS-based clock sources are available in the east and west banks on all Fusion devices.

Figure 2-22 • Clock Input Sources Including CLKBUF, CLKBUF_LVDS/LVPECL, and CLKINT

Flash Memory Block Diagram

A simplified diagram of the flash memory block is shown in Figure 2-33.

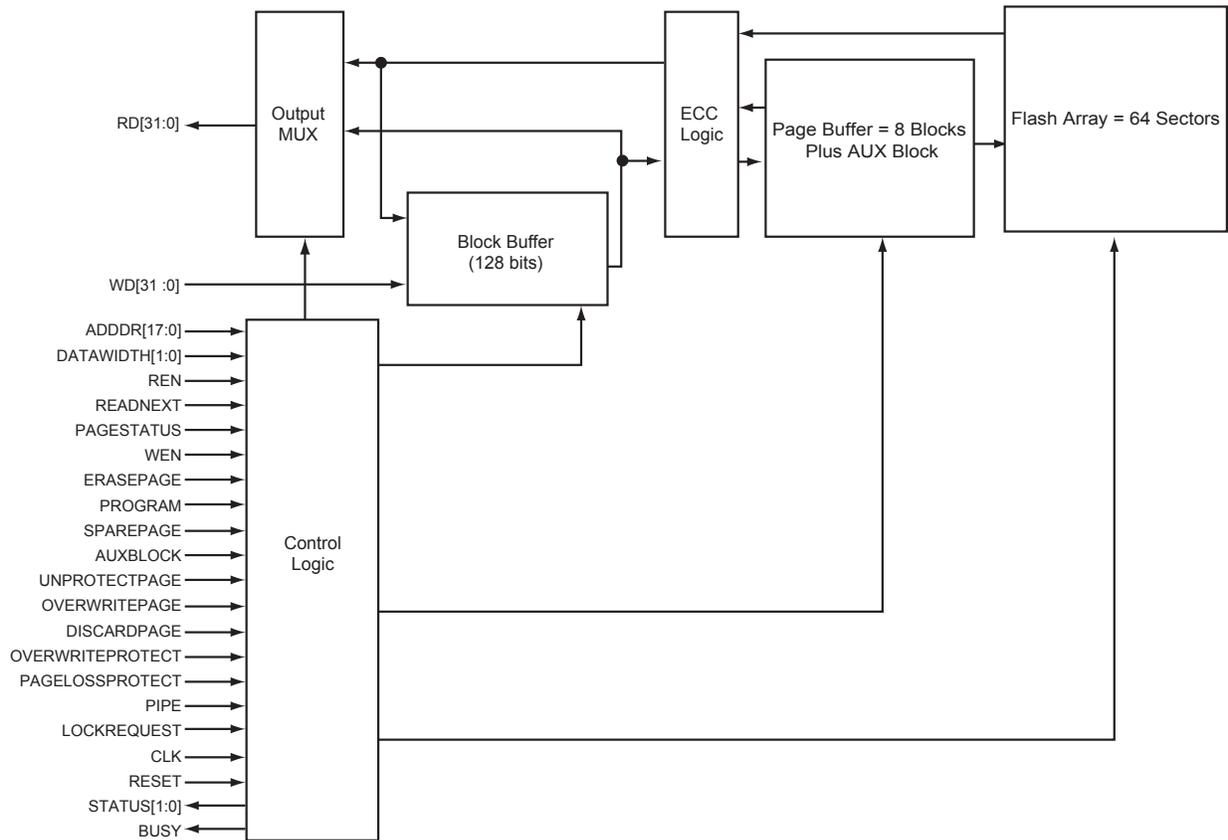


Figure 2-33 • Flash Memory Block Diagram

The logic consists of the following sub-blocks:

- Flash Array
Contains all stored data. The flash array contains 64 sectors, and each sector contains 33 pages of data.
- Page Buffer
A page-wide volatile register. A page contains 8 blocks of data and an AUX block.
- Block Buffer
Contains the contents of the last block accessed. A block contains 128 data bits.
- ECC Logic

The FB stores error correction information with each block to perform single-bit error correction and double-bit error detection on all data blocks.

RAM512X18 Description

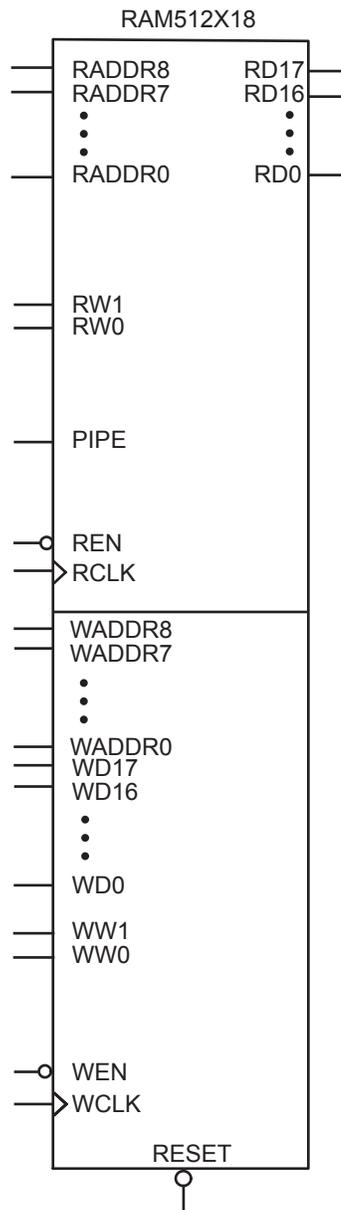


Figure 2-49 • RAM512X18

Direct Digital Input

The AV, AC, and AT pads can also be configured as high-voltage digital inputs (Figure 2-69). As these pads are 12 V-tolerant, the digital input can also be up to 12 V. However, the frequency at which these pads can operate is limited to 10 MHz.

To enable one of these analog input pads to operate as a digital input, its corresponding Digital Input Enable (DENAx_y) pin on the Analog Block must be pulled High, where x is either V, C, or T (for AV, AC, or AT pads, respectively) and y is in the range 0 to 9, corresponding to the appropriate Analog Quad.

When the pad is configured as a digital input, the signal will come out of the Analog Block macro on the appropriate DAXOUT_y pin, where x represents the pad type (V for AV pad, C for AC pad, or T for AT pad) and y represents the appropriate Analog Quad number. Example: If the AT pad in Analog Quad 5 is configured as a digital input, it will come out on the DATOUT5 pin of the Analog Block macro.

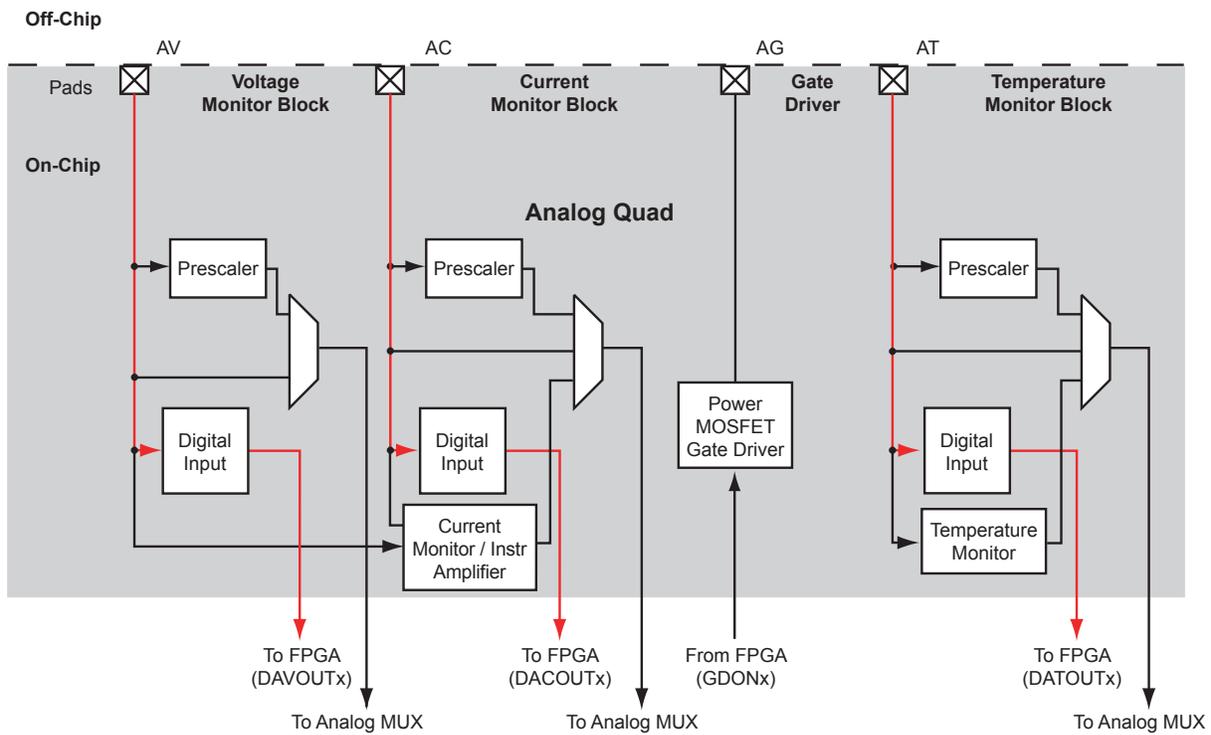


Figure 2-69 • Analog Quad Direct Digital Input Configuration

To initiate a current measurement, the appropriate Current Monitor Strobe (CMSTB) signal on the AB macro must be asserted low for at least t_{CMSLO} in order to discharge the previous measurement. Then CMSTB must be asserted high for at least t_{CMSET} prior to asserting the ADCSTART signal. The CMSTB must remain high until after the SAMPLE signal is de-asserted by the AB macro. Note that the minimum sample time cannot be less than t_{CMSHI} . Figure 2-71 shows the timing diagram of CMSTB in relationship with the ADC control signals.

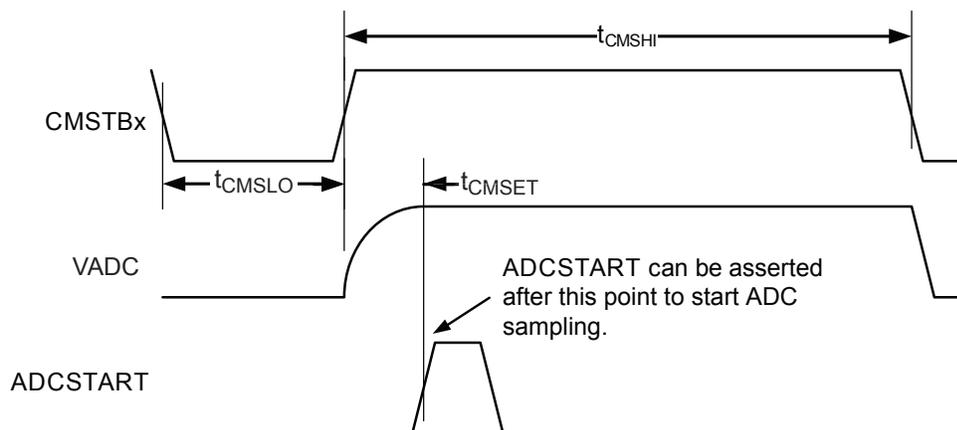


Figure 2-71 • Timing Diagram for Current Monitor Strobe

Figure 2-72 illustrates positive current monitor operation. The differential voltage between AV and AC goes into the 10× amplifier and is then converted by the ADC. For example, a current of 1.5 A is drawn from a 10 V supply and is measured by the voltage drop across a 0.050 Ω sense resistor. The voltage drop is amplified by ten times by the amplifier and then measured by the ADC. The 1.5 A current creates a differential voltage across the sense resistor of 75 mV. This becomes 750 mV after amplification. Thus, the ADC measures a current of 1.5 A as 750 mV. Using an ADC with 8-bit resolution and VAREF of 2.56 V, the ADC result is decimal 75. EQ 3 shows how to compute the current from the ADC result.

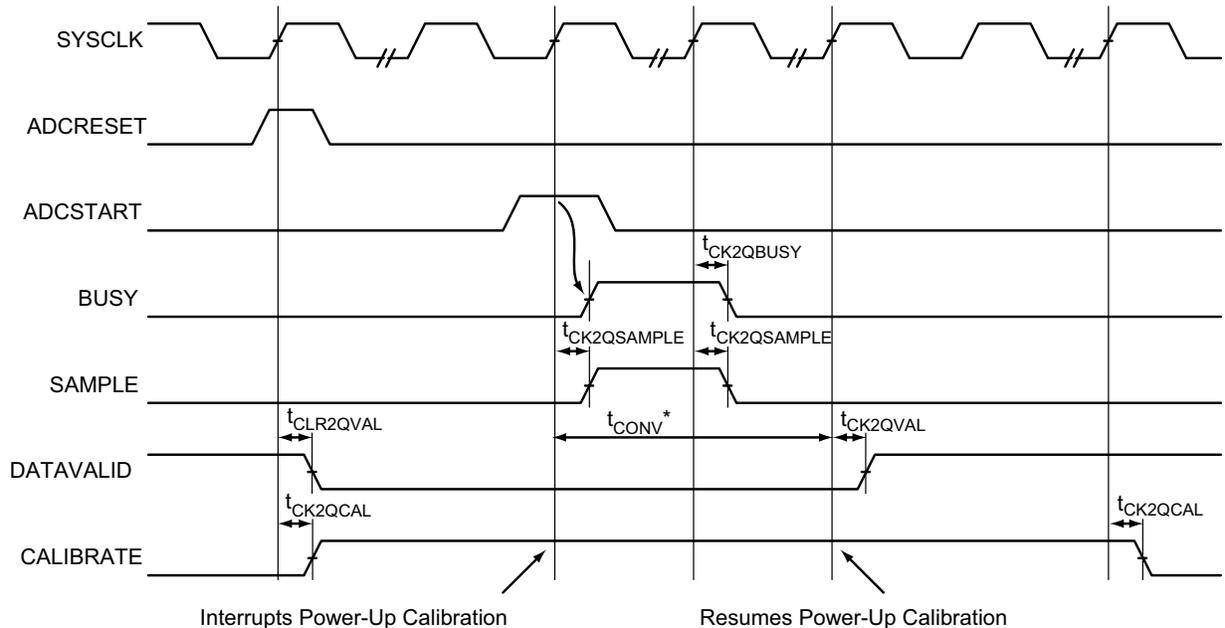
$$I = (ADC \times V_{AREF}) / (10 \times 2^N \times R_{sense})$$

EQ 3

where

- I is the current flowing through the sense resistor
- ADC is the result from the ADC
- VAREF is the Reference voltage
- N is the number of bits
- R_{sense} is the resistance of the sense resistor

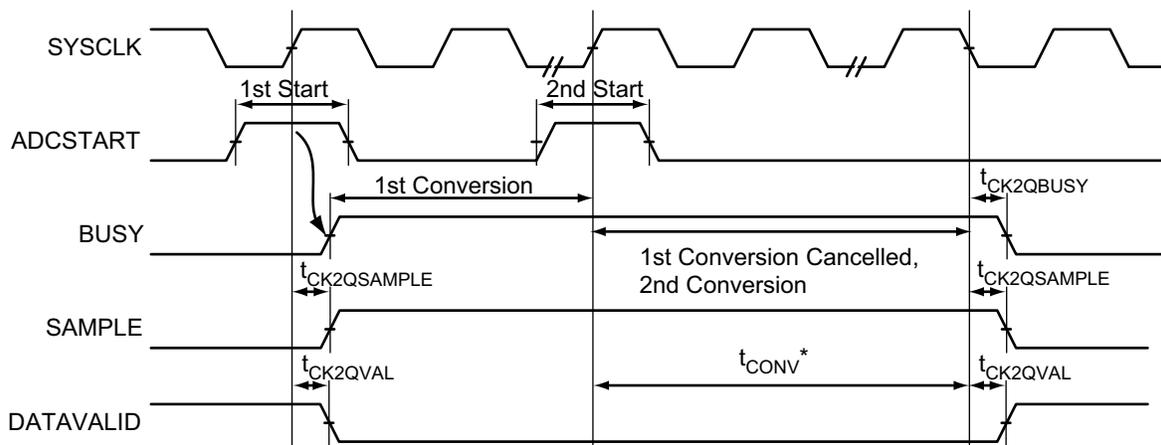
Intra-Conversion



Note: t_{CONV}^* represents the conversion time of the second conversion. See EQ 23 on page 2-109 for calculation of the conversion time, t_{CONV} .

Figure 2-92 • Intra-Conversion Timing Diagram

Injected Conversion



Note: *See EQ 23 on page 2-109 for calculation on the conversion time, t_{CONV} .

Figure 2-93 • Injected Conversion Timing Diagram

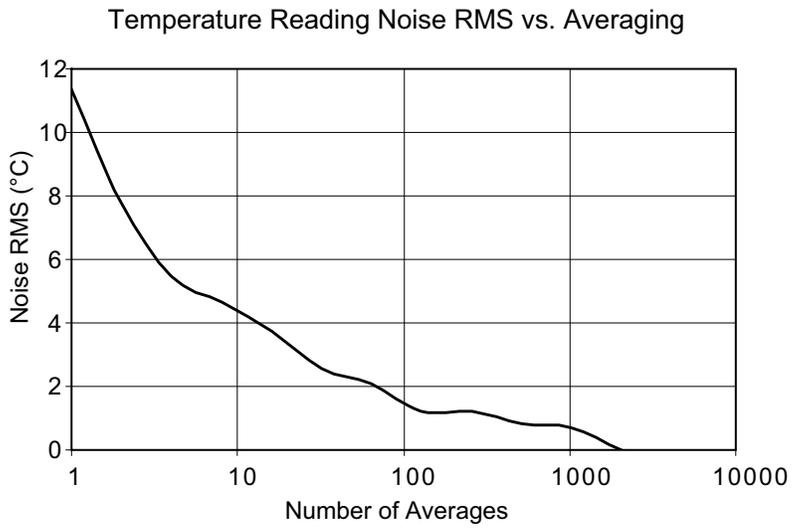


Figure 2-96 • Temperature Reading Noise When Averaging is Used

Table 2-96 • I/O Output Buffer Maximum Resistances ¹ (continued)

| Standard | Drive Strength | R _{PULL-DOWN} (ohms) ² | R _{PULL-UP} (ohms) ³ |
|---|----------------|---|---|
| Applicable to Standard I/O Banks | | | |
| 3.3 V LVTTTL / 3.3 V LVCMOS | 2 mA | 100 | 300 |
| | 4 mA | 100 | 300 |
| | 6 mA | 50 | 150 |
| | 8 mA | 50 | 150 |
| 2.5 V LVCMOS | 2 mA | 100 | 200 |
| | 4 mA | 100 | 200 |
| | 6 mA | 50 | 100 |
| | 8 mA | 50 | 100 |
| 1.8 V LVCMOS | 2 mA | 200 | 225 |
| | 4 mA | 100 | 112 |
| 1.5 V LVCMOS | 2 mA | 200 | 224 |

Notes:

1. These maximum values are provided for informational reasons only. Minimum output buffer resistance values depend on VCC, drive strength selection, temperature, and process. For board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the Microsemi SoC Products Group website: <http://www.microsemi.com/soc/techdocs/models/ibis.html>.
2. $R_{(PULL-DOWN-MAX)} = VOL_{spec} / I_{OL_{spec}}$
3. $R_{(PULL-UP-MAX)} = (VCCImax - VOH_{spec}) / IOH_{spec}$

**Table 2-97 • I/O Weak Pull-Up/Pull-Down Resistances
Minimum and Maximum Weak Pull-Up/Pull-Down Resistance Values**

| VCCI | R _(WEAK PULL-UP) ¹ (ohms) | | R _(WEAK PULL-DOWN) ² (ohms) | |
|-------|--|------|--|-------|
| | Min. | Max. | Min. | Max. |
| 3.3 V | 10 k | 45 k | 10 k | 45 k |
| 2.5 V | 11 k | 55 k | 12 k | 74 k |
| 1.8 V | 18 k | 70 k | 17 k | 110 k |
| 1.5 V | 19 k | 90 k | 19 k | 140 k |

Notes:

1. $R_{(WEAK PULL-UP-MAX)} = (VCCImax - VOH_{spec}) / I_{WEAK PULL-UP-MIN}$
2. $R_{(WEAK PULL-DOWN-MAX)} = VOL_{spec} / I_{WEAK PULL-DOWN-MIN}$

Table 2-114 • 2.5 V LVCMOS Low Slew
 Commercial Temperature Range Conditions: $T_J = 70^\circ\text{C}$, Worst-Case $V_{CC} = 1.425\text{ V}$,
 Worst-Case $V_{CCI} = 2.3\text{ V}$
 Applicable to Advanced I/Os

| Drive Strength | Speed Grade | t_{DOUT} | t_{DP} | t_{DIN} | t_{PY} | t_{EOUT} | t_{ZL} | t_{ZH} | t_{LZ} | t_{HZ} | t_{ZLS} | t_{ZHS} | Units |
|----------------|-------------|------------|----------|-----------|----------|------------|----------|----------|----------|----------|-----------|-----------|-------|
| 4 mA | Std. | 0.66 | 11.40 | 0.04 | 1.31 | 0.43 | 11.22 | 11.40 | 2.68 | 2.20 | 13.45 | 13.63 | ns |
| | -1 | 0.56 | 9.69 | 0.04 | 1.11 | 0.36 | 9.54 | 9.69 | 2.28 | 1.88 | 11.44 | 11.60 | ns |
| | -2 | 0.49 | 8.51 | 0.03 | 0.98 | 0.32 | 8.38 | 8.51 | 2.00 | 1.65 | 10.05 | 10.18 | ns |
| 8 mA | Std. | 0.66 | 7.96 | 0.04 | 1.31 | 0.43 | 8.11 | 7.81 | 3.05 | 2.89 | 10.34 | 10.05 | ns |
| | -1 | 0.56 | 6.77 | 0.04 | 1.11 | 0.36 | 6.90 | 6.65 | 2.59 | 2.46 | 8.80 | 8.55 | ns |
| | -2 | 0.49 | 5.94 | 0.03 | 0.98 | 0.32 | 6.05 | 5.84 | 2.28 | 2.16 | 7.72 | 7.50 | ns |
| 12 mA | Std. | 0.66 | 6.18 | 0.04 | 1.31 | 0.43 | 6.29 | 5.92 | 3.30 | 3.32 | 8.53 | 8.15 | ns |
| | -1 | 0.56 | 5.26 | 0.04 | 1.11 | 0.36 | 5.35 | 5.03 | 2.81 | 2.83 | 7.26 | 6.94 | ns |
| | -2 | 0.49 | 4.61 | 0.03 | 0.98 | 0.32 | 4.70 | 4.42 | 2.47 | 2.48 | 6.37 | 6.09 | ns |
| 16 mA | Std. | 0.66 | 6.18 | 0.04 | 1.31 | 0.43 | 6.29 | 5.92 | 3.30 | 3.32 | 8.53 | 8.15 | ns |
| | -1 | 0.56 | 5.26 | 0.04 | 1.11 | 0.36 | 5.35 | 5.03 | 2.81 | 2.83 | 7.26 | 6.94 | ns |
| | -2 | 0.49 | 4.61 | 0.03 | 0.98 | 0.32 | 4.70 | 4.42 | 2.47 | 2.48 | 6.37 | 6.09 | ns |
| 24 mA | Std. | 0.66 | 6.18 | 0.04 | 1.31 | 0.43 | 6.29 | 5.92 | 3.30 | 3.32 | 8.53 | 8.15 | ns |
| | -1 | 0.56 | 5.26 | 0.04 | 1.11 | 0.36 | 5.35 | 5.03 | 2.81 | 2.83 | 7.26 | 6.94 | ns |
| | -2 | 0.49 | 4.61 | 0.03 | 0.98 | 0.32 | 4.70 | 4.42 | 2.47 | 2.48 | 6.37 | 6.09 | ns |

Note: For the derating values at specific junction temperature and voltage supply levels, refer to [Table 3-7](#) on [page 3-9](#).

Voltage Referenced I/O Characteristics

3.3 V GTL

Gunning Transceiver Logic is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open-drain output buffer. The VCCI pin should be connected to 3.3 V.

Table 2-138 • Minimum and Maximum DC Input and Output Levels

| 3.3 V GTL Drive Strength | VIL | | VIH | | VOL | VOH | IOL | IOH | IOSL | IOSH | IIL ¹ | IIH ² |
|-----------------------------|--------|-------------|-------------|--------|--------|--------|-----|-----|-----------------|-----------------|------------------|------------------|
| | Min. V | Max. V | Min. V | Max. V | Max. V | Min. V | mA | mA | mA ³ | mA ³ | μA ⁴ | μA ⁴ |
| 20 mA ³ | -0.3 | VREF - 0.05 | VREF + 0.05 | 3.6 | 0.4 | - | 20 | 20 | 181 | 268 | 10 | 10 |

Notes:

1. IIL is the input leakage current per I/O pin over recommended operation conditions where $-0.3\text{ V} < V_{IN} < V_{IL}$.
2. IIH is the input leakage current per I/O pin over recommended operating conditions $V_{IH} < V_{IN} < V_{CCI}$. Input current is larger when operating outside recommended ranges.
3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
4. Currents are measured at 85°C junction temperature.

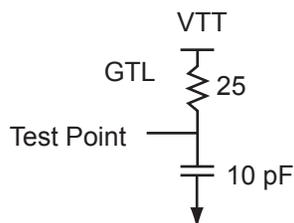


Figure 2-124 • AC Loading

Table 2-139 • AC Waveforms, Measuring Points, and Capacitive Loads

| Input Low (V) | Input High (V) | Measuring Point* (V) | VREF (typ.) (V) | VTT (typ.) (V) | C _{LOAD} (pF) |
|---------------|----------------|----------------------|-----------------|----------------|------------------------|
| VREF - 0.05 | VREF + 0.05 | 0.8 | 0.8 | 1.2 | 10 |

Note: *Measuring point = Vtrip. See Table 2-90 on page 2-166 for a complete table of trip points.

Timing Characteristics

Table 2-140 • 3.3 V GTL

Commercial Temperature Range Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V, VREF = 0.8 V

| Speed Grade | t _{DOUT} | t _{DP} | t _{DIN} | t _{PY} | t _{EOUT} | t _{ZL} | t _{ZH} | t _{LZ} | t _{HZ} | t _{ZLS} | t _{ZHS} | Units |
|-------------|-------------------|-----------------|------------------|-----------------|-------------------|-----------------|-----------------|-----------------|-----------------|------------------|------------------|-------|
| Std. | 0.66 | 2.08 | 0.04 | 2.93 | 0.43 | 2.04 | 2.08 | | | 4.27 | 4.31 | ns |
| -1 | 0.56 | 1.77 | 0.04 | 2.50 | 0.36 | 1.73 | 1.77 | | | 3.63 | 3.67 | ns |
| -2 | 0.49 | 1.55 | 0.03 | 2.19 | 0.32 | 1.52 | 1.55 | | | 3.19 | 3.22 | ns |

Note: For the derating values at specific junction temperature and voltage supply levels, refer to Table 3-7 on page 3-9.

Output Register

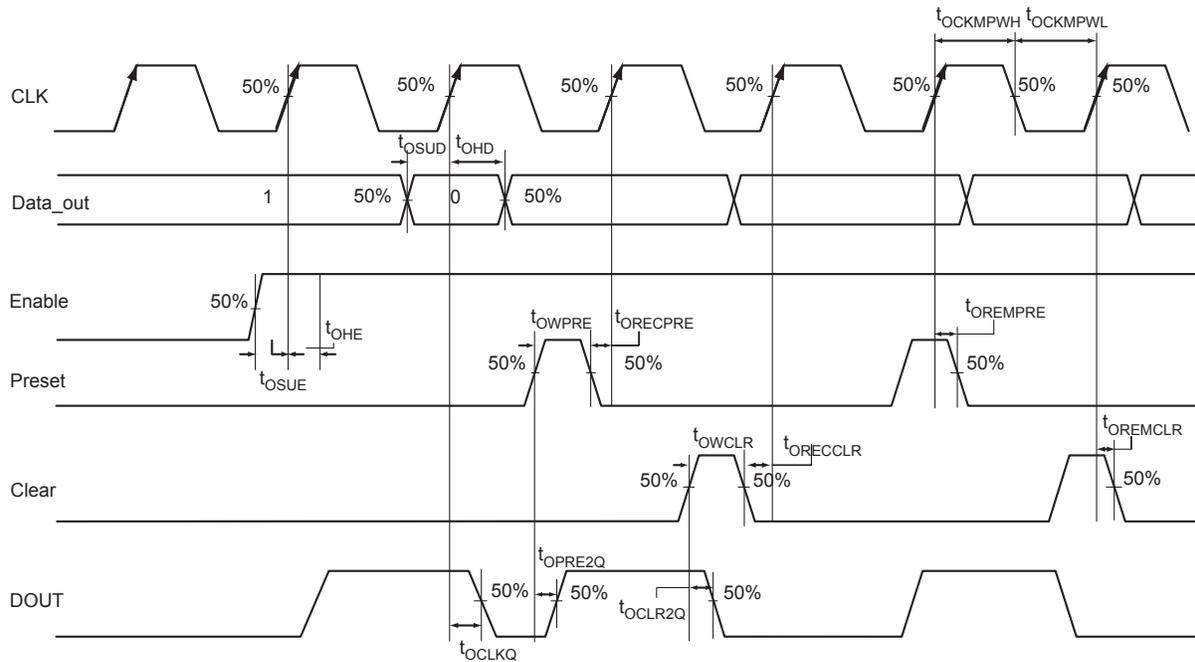


Figure 2-140 • Output Register Timing Diagram

Timing Characteristics

Table 2-177 • Output Data Register Propagation Delays
Commercial Temperature Range Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V

| Parameter | Description | -2 | -1 | Std. | Units |
|----------------------|--|------|------|------|-------|
| t _{OCLKQ} | Clock-to-Q of the Output Data Register | 0.59 | 0.67 | 0.79 | ns |
| t _{OSUD} | Data Setup Time for the Output Data Register | 0.31 | 0.36 | 0.42 | ns |
| t _{OHD} | Data Hold Time for the Output Data Register | 0.00 | 0.00 | 0.00 | ns |
| t _{OSUE} | Enable Setup Time for the Output Data Register | 0.44 | 0.50 | 0.59 | ns |
| t _{OHE} | Enable Hold Time for the Output Data Register | 0.00 | 0.00 | 0.00 | ns |
| t _{OCLR2Q} | Asynchronous Clear-to-Q of the Output Data Register | 0.80 | 0.91 | 1.07 | ns |
| t _{OPRE2Q} | Asynchronous Preset-to-Q of the Output Data Register | 0.80 | 0.91 | 1.07 | ns |
| t _{OREMCLR} | Asynchronous Clear Removal Time for the Output Data Register | 0.00 | 0.00 | 0.00 | ns |
| t _{ORECCLR} | Asynchronous Clear Recovery Time for the Output Data Register | 0.22 | 0.25 | 0.30 | ns |
| t _{OREMPRE} | Asynchronous Preset Removal Time for the Output Data Register | 0.00 | 0.00 | 0.00 | ns |
| t _{ORECPRE} | Asynchronous Preset Recovery Time for the Output Data Register | 0.22 | 0.25 | 0.30 | ns |
| t _{OWCLR} | Asynchronous Clear Minimum Pulse Width for the Output Data Register | 0.22 | 0.25 | 0.30 | ns |
| t _{OWPRE} | Asynchronous Preset Minimum Pulse Width for the Output Data Register | 0.22 | 0.25 | 0.30 | ns |
| t _{OCKMPWH} | Clock Minimum Pulse Width High for the Output Data Register | 0.36 | 0.41 | 0.48 | ns |
| t _{OCKMPWL} | Clock Minimum Pulse Width Low for the Output Data Register | 0.32 | 0.37 | 0.43 | ns |

Note: For the derating values at specific junction temperature and voltage supply levels, refer to [Table 3-7](#) on [page 3-9](#).

Table 3-8 • AFS1500 Quiescent Supply Current Characteristics (continued)

| Parameter | Description | Conditions | Temp. | Min. | Typ. | Max. | Unit |
|-----------|-----------------------------|---|------------------------|------|------|------|------|
| IJTAG | JTAG I/O quiescent current | Operational standby ⁴ , VJTAG = 3.63 V | T _J = 25°C | | 80 | 100 | μA |
| | | | T _J = 85°C | | 80 | 100 | μA |
| | | | T _J = 100°C | | 80 | 100 | μA |
| | | Standby mode ⁵ or Sleep mode ⁶ , VJTAG = 0 V | | | 0 | 0 | μA |
| IPP | Programming supply current | Non-programming mode, VPUMP = 3.63 V | T _J = 25°C | | 39 | 80 | μA |
| | | | T _J = 85°C | | 40 | 80 | μA |
| | | | T _J = 100°C | | 40 | 80 | μA |
| | | Standby mode ⁵ or Sleep mode ⁶ , VPUMP = 0 V | | | 0 | 0 | μA |
| ICCNVM | Embedded NVM current | Reset asserted, V _{CCNVM} = 1.575 V | T _J = 25°C | | 50 | 150 | μA |
| | | | T _J = 85°C | | 50 | 150 | μA |
| | | | T _J = 100°C | | 50 | 150 | μA |
| ICCPLL | 1.5 V PLL quiescent current | Operational standby , VCCPLL = 1.575 V | T _J = 25°C | | 130 | 200 | μA |
| | | | T _J = 85°C | | 130 | 200 | μA |
| | | | T _J = 100°C | | 130 | 200 | μA |

Notes:

1. ICC is the 1.5 V power supplies, ICC and ICC15A.
2. ICC33A includes ICC33A, ICC33PMP, and ICCOSC.
3. ICCI includes all ICCI0, ICCI1, ICCI2, and ICCI4.
4. Operational standby is when the Fusion device is powered up, all blocks are used, no I/O is toggling, Voltage Regulator is loaded with 200 mA, VCC33PMP is ON, XTAL is ON, and ADC is ON.
5. XTAL is configured as high gain, VCC = VJTAG = VPUMP = 0 V.
6. Sleep Mode, VCC = VJTAG = VPUMP = 0 V.

Table 3-11 • AFS090 Quiescent Supply Current Characteristics (continued)

| Parameter | Description | Conditions | Temp. | Min | Typ | Max | Unit |
|-----------|-----------------------------|--|------------------------|-----|-----|-----|------|
| ICCNVM | Embedded NVM current | Reset asserted, VCCNVM = 1.575 V | T _J = 25°C | | 10 | 40 | μA |
| | | | T _J = 85°C | | 14 | 40 | μA |
| | | | T _J = 100°C | | 14 | 40 | μA |
| ICCPLL | 1.5 V PLL quiescent current | Operational standby, VCCPLL = 1.575 V | T _J = 25°C | | 65 | 100 | μA |
| | | | T _J = 85°C | | 65 | 100 | μA |
| | | | T _J = 100°C | | 65 | 100 | μA |

Notes:

1. ICC is the 1.5 V power supplies, ICC, ICCPLL, ICC15A, ICCNVM.
2. ICC33A includes ICC33A, ICC33PMP, and ICCOSC.
3. ICCI includes all ICCI0, ICCI1, and ICCI2.
4. Operational standby is when the Fusion device is powered up, all blocks are used, no I/O is toggling, Voltage Regulator is loaded with 200 mA, VCC33PMP is ON, XTAL is ON, and ADC is ON.
5. XTAL is configured as high gain, VCC = VJTAG = VPUMP = 0 V.
6. Sleep Mode, VCC = VJTAG = VPUMP = 0 V.

Methodology

Total Power Consumption— P_{TOTAL}

Operating Mode, Standby Mode, and Sleep Mode

$$P_{TOTAL} = P_{STAT} + P_{DYN}$$

P_{STAT} is the total static power consumption.

P_{DYN} is the total dynamic power consumption.

Total Static Power Consumption— P_{STAT}

Operating Mode

$$P_{STAT} = PDC1 + (N_{NVM-BLOCKS} * PDC4) + PDC5 + (N_{QUADS} * PDC6) + (N_{INPUTS} * PDC7) + (N_{OUTPUTS} * PDC8) + (N_{PLLS} * PDC9)$$

$N_{NVM-BLOCKS}$ is the number of NVM blocks available in the device.

N_{QUADS} is the number of Analog Quads used in the design.

N_{INPUTS} is the number of I/O input buffers used in the design.

$N_{OUTPUTS}$ is the number of I/O output buffers used in the design.

N_{PLLS} is the number of PLLs available in the device.

Standby Mode

$$P_{STAT} = PDC2$$

Sleep Mode

$$P_{STAT} = PDC3$$

Total Dynamic Power Consumption— P_{DYN}

Operating Mode

$$P_{DYN} = P_{CLOCK} + P_{S-CELL} + P_{C-CELL} + P_{NET} + P_{INPUTS} + P_{OUTPUTS} + P_{MEMORY} + P_{PLL} + P_{NVM} + P_{XTL-OSC} + P_{RC-OSC} + P_{AB}$$

Standby Mode

$$P_{DYN} = P_{XTL-OSC}$$

Sleep Mode

$$P_{DYN} = 0 \text{ W}$$

Global Clock Dynamic Contribution— P_{CLOCK}

Operating Mode

$$P_{CLOCK} = (PAC1 + N_{SPINE} * PAC2 + N_{ROW} * PAC3 + N_{S-CELL} * PAC4) * F_{CLK}$$

N_{SPINE} is the number of global spines used in the user design—guidelines are provided in the "Spine Architecture" section of the Global Resources chapter in the [Fusion and Extended Temperature Fusion FPGA Fabric User's Guide](#).

N_{ROW} is the number of VersaTile rows used in the design—guidelines are provided in the "Spine Architecture" section of the Global Resources chapter in the [Fusion and Extended Temperature Fusion FPGA Fabric User's Guide](#).

F_{CLK} is the global clock signal frequency.

N_{S-CELL} is the number of VersaTiles used as sequential modules in the design.

Standby Mode and Sleep Mode

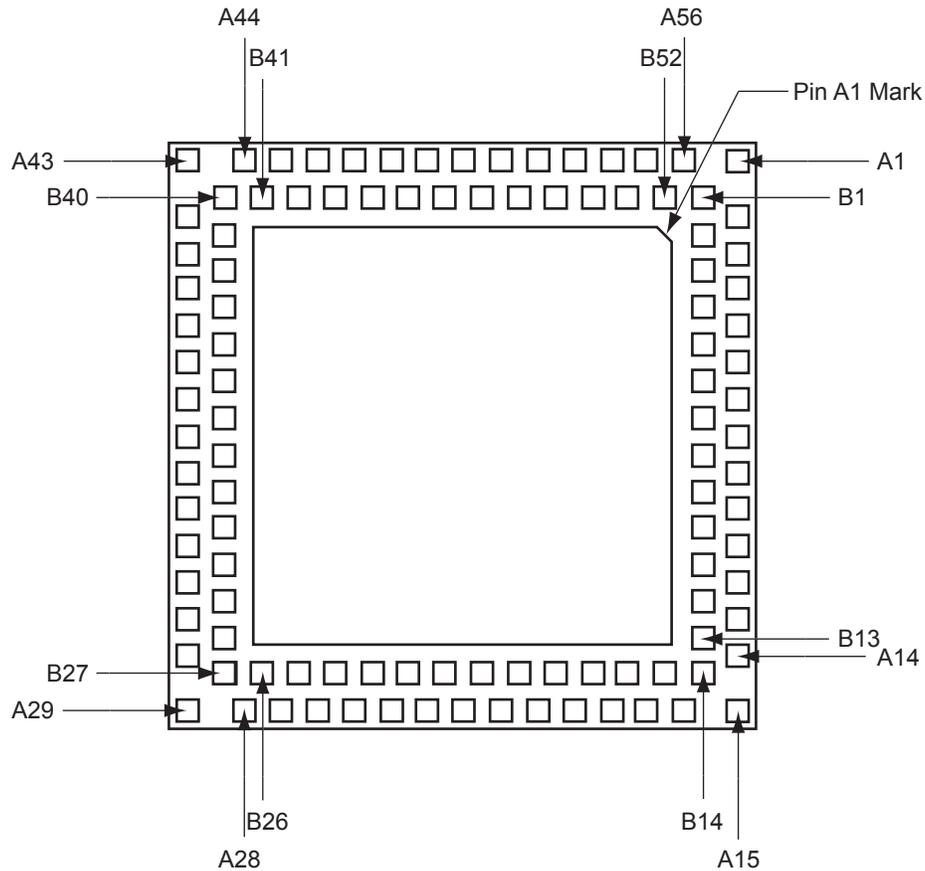
$$P_{CLOCK} = 0 \text{ W}$$

Sequential Cells Dynamic Contribution— P_{S-CELL}

Operating Mode

4 – Package Pin Assignments

QN108



Note: The die attach paddle center of the package is tied to ground (GND).

Note

For Package Manufacturing and Environmental information, visit the Resource Center at <http://www.microsemi.com/soc/products/solutions/package/default.aspx>.

| FG484 | | |
|------------|-----------------|------------------|
| Pin Number | AFS600 Function | AFS1500 Function |
| L17 | VCCIB2 | VCCIB2 |
| L18 | IO46PDB2V0 | IO69PDB2V0 |
| L19 | GCA1/IO45PDB2V0 | GCA1/IO64PDB2V0 |
| L20 | VCCIB2 | VCCIB2 |
| L21 | GCC0/IO43NDB2V0 | GCC0/IO62NDB2V0 |
| L22 | GCC1/IO43PDB2V0 | GCC1/IO62PDB2V0 |
| M1 | NC | IO103PDB4V0 |
| M2 | XTAL1 | XTAL1 |
| M3 | VCCIB4 | VCCIB4 |
| M4 | GNDOSC | GNDOSC |
| M5 | GFC0/IO72NDB4V0 | GFC0/IO107NDB4V0 |
| M6 | VCCIB4 | VCCIB4 |
| M7 | GFB0/IO71NDB4V0 | GFB0/IO106NDB4V0 |
| M8 | VCCIB4 | VCCIB4 |
| M9 | VCC | VCC |
| M10 | GND | GND |
| M11 | VCC | VCC |
| M12 | GND | GND |
| M13 | VCC | VCC |
| M14 | GND | GND |
| M15 | VCCIB2 | VCCIB2 |
| M16 | IO48NDB2V0 | IO70NDB2V0 |
| M17 | VCCIB2 | VCCIB2 |
| M18 | IO46NDB2V0 | IO69NDB2V0 |
| M19 | GCA0/IO45NDB2V0 | GCA0/IO64NDB2V0 |
| M20 | VCCIB2 | VCCIB2 |
| M21 | GCB0/IO44NDB2V0 | GCB0/IO63NDB2V0 |
| M22 | GCB1/IO44PDB2V0 | GCB1/IO63PDB2V0 |
| N1 | NC | IO103NDB4V0 |
| N2 | GND | GND |
| N3 | IO68PDB4V0 | IO101PDB4V0 |
| N4 | NC | IO100NPB4V0 |
| N5 | GND | GND |
| N6 | NC | IO99PDB4V0 |
| N7 | NC | IO97PDB4V0 |

| FG484 | | |
|------------|-----------------|------------------|
| Pin Number | AFS600 Function | AFS1500 Function |
| N8 | GND | GND |
| N9 | GND | GND |
| N10 | VCC | VCC |
| N11 | GND | GND |
| N12 | VCC | VCC |
| N13 | GND | GND |
| N14 | VCC | VCC |
| N15 | GND | GND |
| N16 | GDB2/IO56PDB2V0 | GDB2/IO83PDB2V0 |
| N17 | NC | IO78PDB2V0 |
| N18 | GND | GND |
| N19 | IO47NDB2V0 | IO72NDB2V0 |
| N20 | IO47PDB2V0 | IO72PDB2V0 |
| N21 | GND | GND |
| N22 | IO49PDB2V0 | IO71PDB2V0 |
| P1 | GFA1/IO70PDB4V0 | GFA1/IO105PDB4V0 |
| P2 | GFA0/IO70NDB4V0 | GFA0/IO105NDB4V0 |
| P3 | IO68NDB4V0 | IO101NDB4V0 |
| P4 | IO65PDB4V0 | IO96PDB4V0 |
| P5 | IO65NDB4V0 | IO96NDB4V0 |
| P6 | NC | IO99NDB4V0 |
| P7 | NC | IO97NDB4V0 |
| P8 | VCCIB4 | VCCIB4 |
| P9 | VCC | VCC |
| P10 | GND | GND |
| P11 | VCC | VCC |
| P12 | GND | GND |
| P13 | VCC | VCC |
| P14 | GND | GND |
| P15 | VCCIB2 | VCCIB2 |
| P16 | IO56NDB2V0 | IO83NDB2V0 |
| P17 | NC | IO78NDB2V0 |
| P18 | GDA1/IO54PDB2V0 | GDA1/IO81PDB2V0 |
| P19 | GDB1/IO53PDB2V0 | GDB1/IO80PDB2V0 |
| P20 | IO51NDB2V0 | IO73NDB2V0 |